



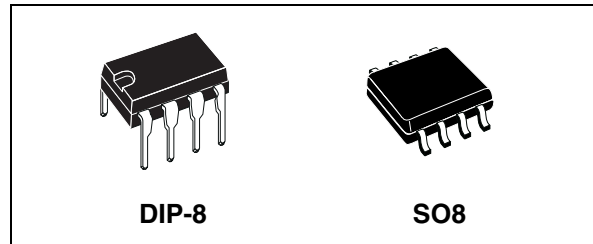
**THE DATASHEET OF
L6571AD013TR**



High voltage half bridge driver with oscillator

Features

- High voltage rail up to 600 V
- BCD off line technology
- 15.6 V Zener clamp on V_s
- Driver current capability:
 - Sink current = 270 mA
 - Source current = 170 mA
- Very low start up current: 150 mA
- Undervoltage lockout with hysteresis
- Programmable oscillator frequency
- Dead time 1.25 μ s (L6571A) or 0.72 μ s (L6571B)
- dV/dt immunity up to ± 50 V/ns
- ESD protection



can be programmed using external resistor and capacitor.

The internal circuitry of the device allows it to be driven also by external logic signal.

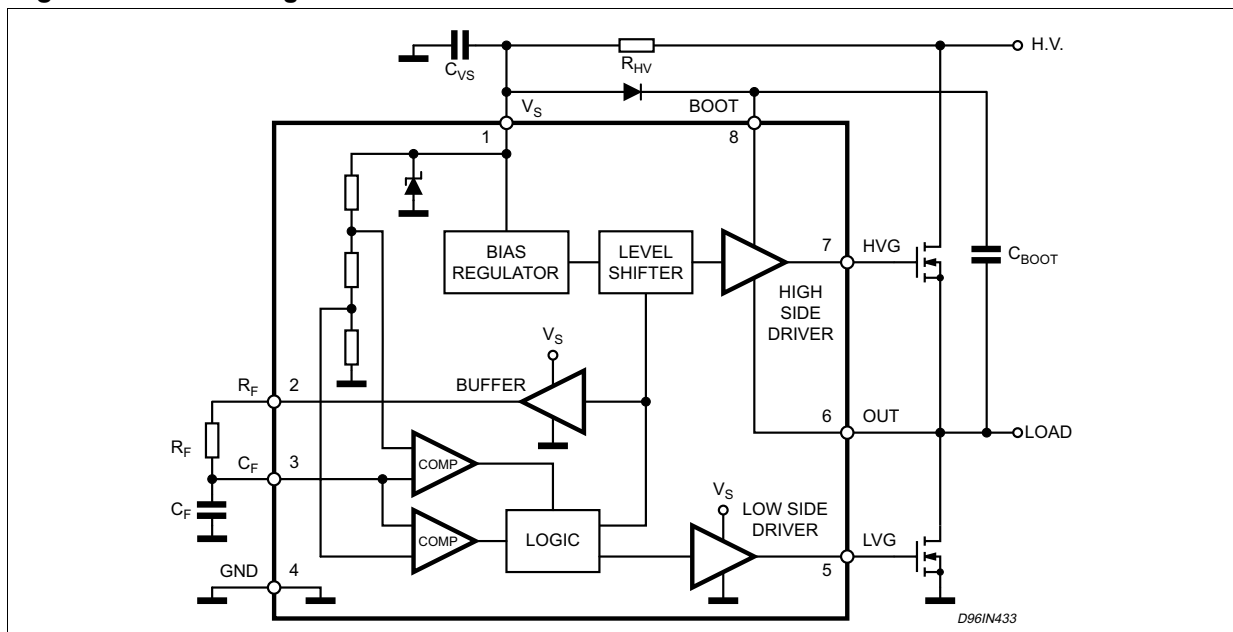
The output drivers are designed to drive external nchannel power MOSFET and IGBT. The internal logic assures a dead time to avoid cross-conduction of the power devices.

Two version are available: L6571A and L6571B. They differ in the internal dead time: 1.25 μ s and 0.72 μ s (typ.)

Description

The device is a high voltage half bridge driver with built in oscillator. The frequency of the oscillator

Figure 1. Block diagram



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1 Maximum ratings

1.1 Absolute maximum ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
$I_S^{(1)}$	Supply current	25	mA
V_{CF}	Oscillator resistor voltage	18	V
V_{LVG}	Low side switch gate output	14.6	V
V_{OUT}	High side switch source output	-1 to $V_{BOOT} - 18$	V
V_{HVG}	High side switch gate output	-1 to V_{BOOT}	V
V_{BOOT}	Floating supply voltage	618	V
$V_{BOOT/OUT}$	Floating supply vs OUT voltage	18	V
dV_{BOOT}/dt	VBOOT slew rate (Repetitive)	± 50	V/ns
dV_{OUT}/dt	VOOUT slew rate (Repetitive)	± 50	V/ns
T_{stg}	Storage temperature	-40 to 150	°C
T_J	Junction temperature	-40 to 150	°C
T_{amb}	Ambient temperature (Operative)	-40 to 125	°C

1. The device has an internal zener clamp between GND and VS (typical 15.6 V). Therefore the circuit should not be driven by a DC low impedance power source.

Note: ESD immunity for pins 6, 7 and 8 is guaranteed up to 900 V (human body model)

1.2 Thermal data

Table 2. Thermal data

Symbol	Parameter	MDIP8	SO8	Unit
R_{thJA}	Thermal resistance junction-ambient max	100	150	°C/W

1.3 Recommended operating conditions

Table 3. Recommended operating conditions

Symbol	Parameter	Min.	Max.	Unit
V_S	Supply voltage	10	VCL	V
V_{BOOT}	Floating supply voltage	-	500	V
V_{OUT}	High side switch source output	-1	$V_{BOOT} - VCL$	V
f_{out}	Oscillation frequency		200	kHz

2 Pin connection

Figure 2. Pin connection

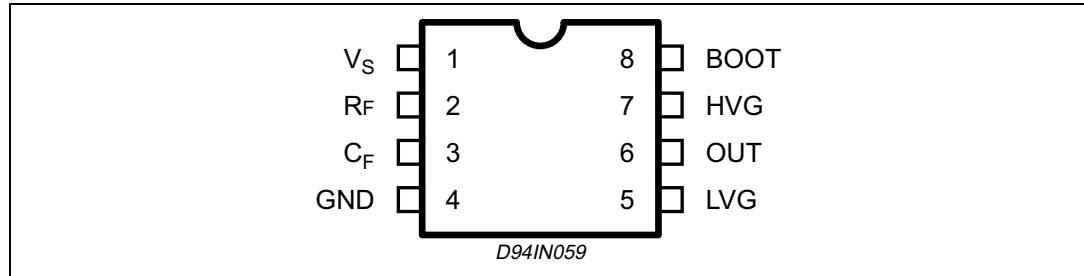


Table 4. Pin description

N°	Pin	Description
1	VS	Supply input voltage with internal clamp [typ. 15.6V]
2	RF	Oscillator timing resistor pin. A buffer set alternatively to VS and GND can provide current to the external resistor RF connected between pin 2 and 3. Alternatively, the signal on pin 2 can be used also to drive another IC (i.e. another L6569/71 to drive a full H-bridge)
3	CF	Oscillator timing capacitor pin. A capacitor connected between this pin and GND fixes (together with RF) the oscillating frequency. Alternatively an external logic signal can be applied to the pin to drive the IC.
4	GND	Ground
5	LVG	Low side driver output. The output stage can deliver 170mA source and 270mA sink [typ.values].
6	OUT	Upper driver floating reference
7	HVG	High side driver output. The output stage can deliver 170mA source and 270mA sink [typ.values].
8	BOOT	Bootstrap voltage supply. It is the upper driver floating supply.

3 Electrical data

$V_S = 12V$; $V_{BOOT} - V_{OUT} = 12V$; $T_j = 25\text{ }^\circ\text{C}$; unless otherwise specified.

Table 5. Electrical characteristics

Symbol	Pin	Parameter	Test Condition	Min.	Typ.	Max.	Unit
$V_{SUV P}$	1	VS turn on threshold		8.3	9	9.7	V
$V_{SUV N}$		VS turn off threshold		7.3	8	8.7	V
$V_{SUV H}$		VS hysteresis		0.7	1	1.3	V
V_{CL}		VS clamping voltage	$I_S = 5\text{ mA}$	14.6	15.6	16.6	V
I_{SU}		Start up current	$V_S < V_{SUV N}$		150	250	μA
I_q		Quiescent current	$V_S > V_{SUV P}$		500	700	μA
I_{BOOTLK}	8	Leakage current BOOT pin vs GND	$V_{BOOT} = 580V$			5	μA
I_{OUTLK}	6	Leakage current OUT pin vs GND	$V_{OUT} = 562V$			5	μA
$I_{HVG SO}$	7	High side driver source current	$V_{HVG} = 6V$	110	175		mA
$I_{HVG SI}$		High side driver sink current	$V_{HVG} = 6V$	190	275		mA
$I_{LVG SO}$	5	Low side driver source current	$V_{LVG} = 6V$	110	175		mA
$I_{LVG SI}$		Low side driver sink current	$V_{LVG} = 6V$	190	275		mA
$V_{RF ON}$	2	RF high level output voltage	$I_{RF} = 1\text{mA}$	$V_S - 0.05$		$V_S - 0.2$	V
$V_{RF OFF}$		RF low level output voltage	$I_{RF} = -1\text{mA}$	50		200	mV
V_{CFU}	3	CF upper threshold		7.7	8	8.2	V
V_{CFL}		CF lower threshold		3.80	4	4.3	V
t_d		Internal dead time	L6571A L6571B	0.85 0.50	1.25 0.72	1.65 0.94	μs μs
DC		Duty cycle, ratio between dead Time + conduction time of high Side and low side drivers		0.45	0.5	0.55	
I_{AVE}	1	Average current from Vs	No Load, $f_s = 60\text{KHz}$		1.2	1.5	mA
f_{out}	6	Oscillation frequency	$RT = 12\text{K}$; $CT = 1\text{nF}$	57	60	63	kHz

4 Oscillator frequency

The frequency of the internal oscillator can be programmed using external resistor and capacitor.

The nominal oscillator frequency can be calculated using the following equation:

Equation 1

$$f_{osc} = \frac{1}{2 \cdot R_F \cdot C_F \cdot \ln 2} = \frac{1}{1.3863 \cdot R_F \cdot C_F}$$

Where R_F and C_F are the external resistor and capacitor.

The device can be driven in "shut down" condition keeping the C_F pin close to GND, but some cares have to be taken:

1. When C_F is to GND the high side driver is off and the low side is on
2. The forced discharge of the oscillator capacitor C_F must not be shorter than 1us: a simple way to do this is to limit the current discharge with a resistive path imposing $R \cdot C_F > 1 \mu s$ (see fig.1)

Figure 3. Fault signal

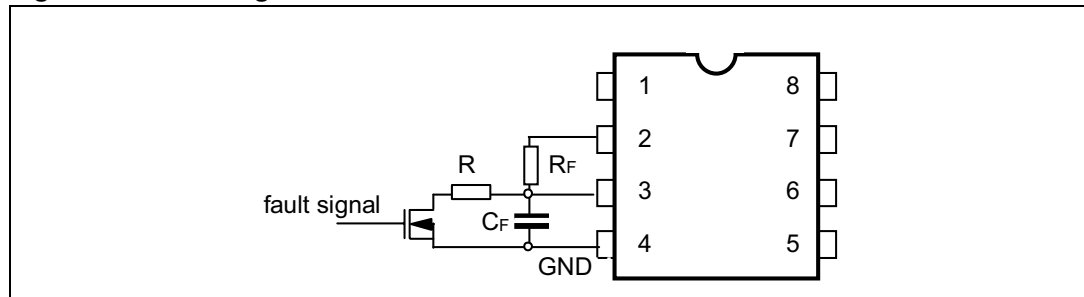


Figure 4. Waveforms

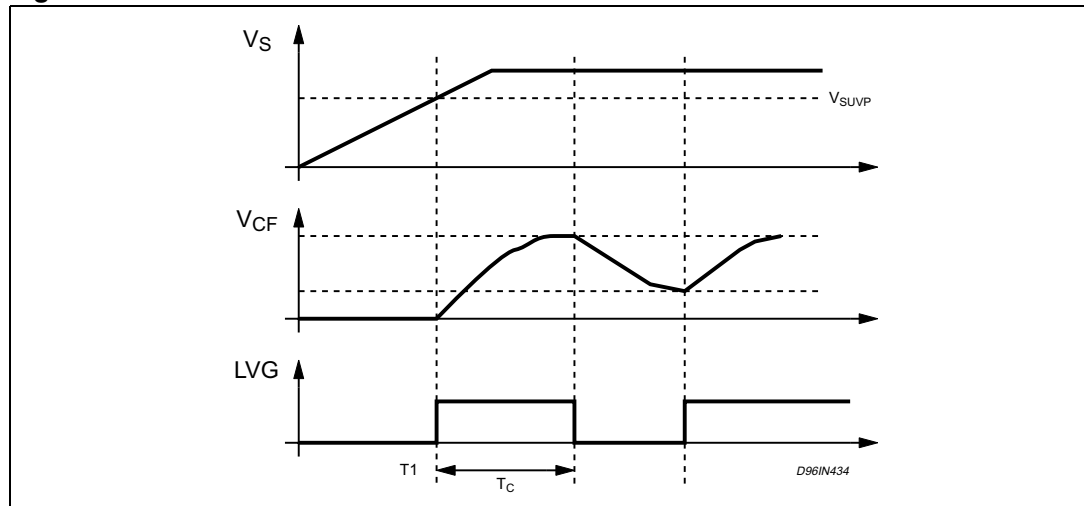


Figure 5. Typical dead time vs. temperature dependency (L6571A)

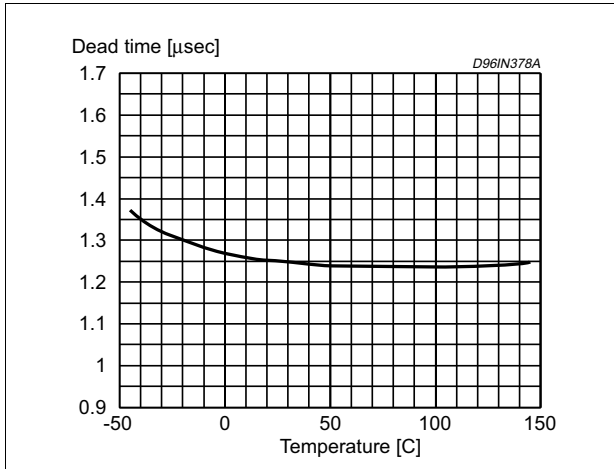


Figure 6. Typical rise and fall times vs. load capacitance

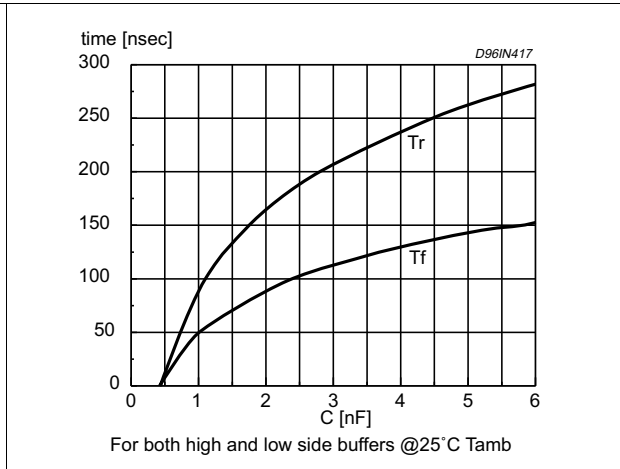


Figure 7. Typical frequency vs temperature dependency

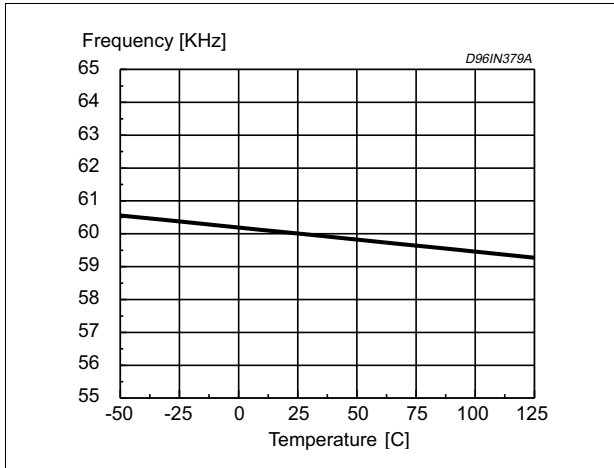


Figure 8. Quiescent current vs. supply voltage

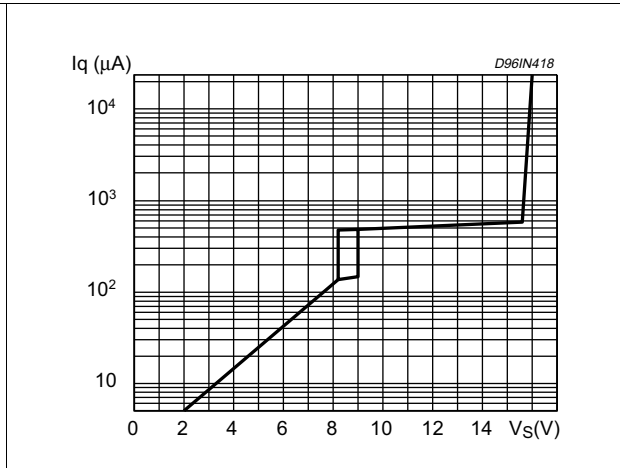
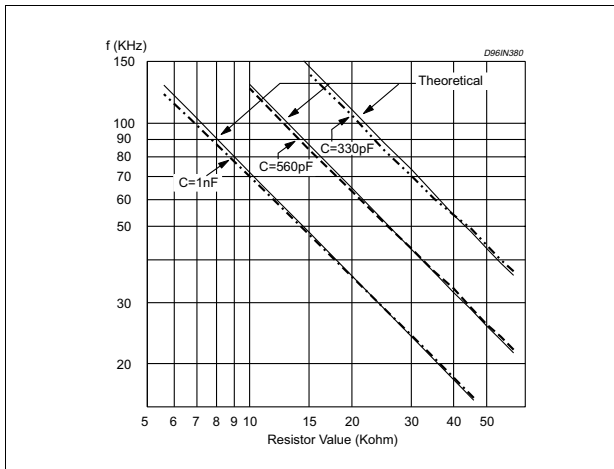


Figure 9. Typical and theoretical oscillator frequency vs resistor value



5 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Figure 10. DIP-8 mechanical data

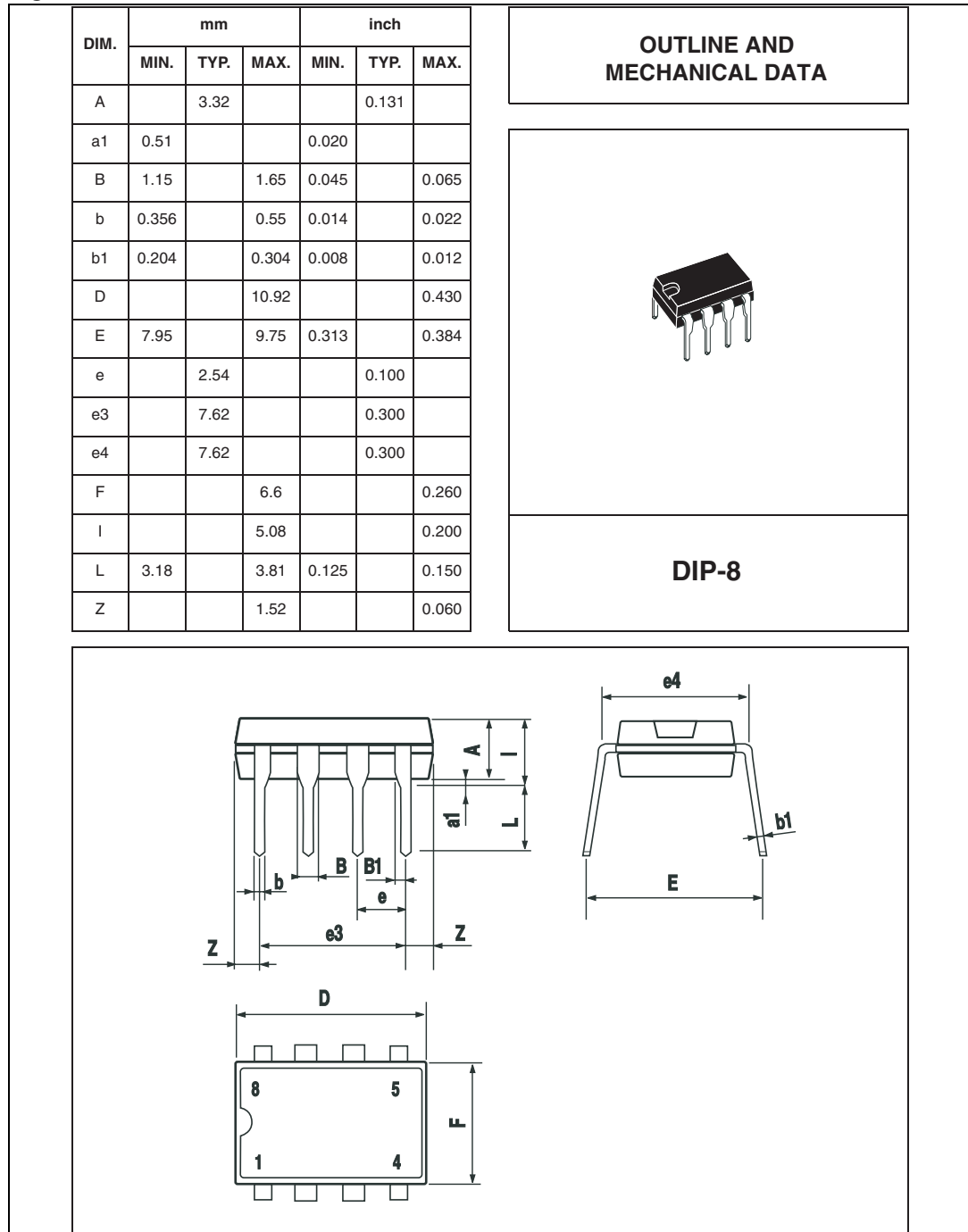
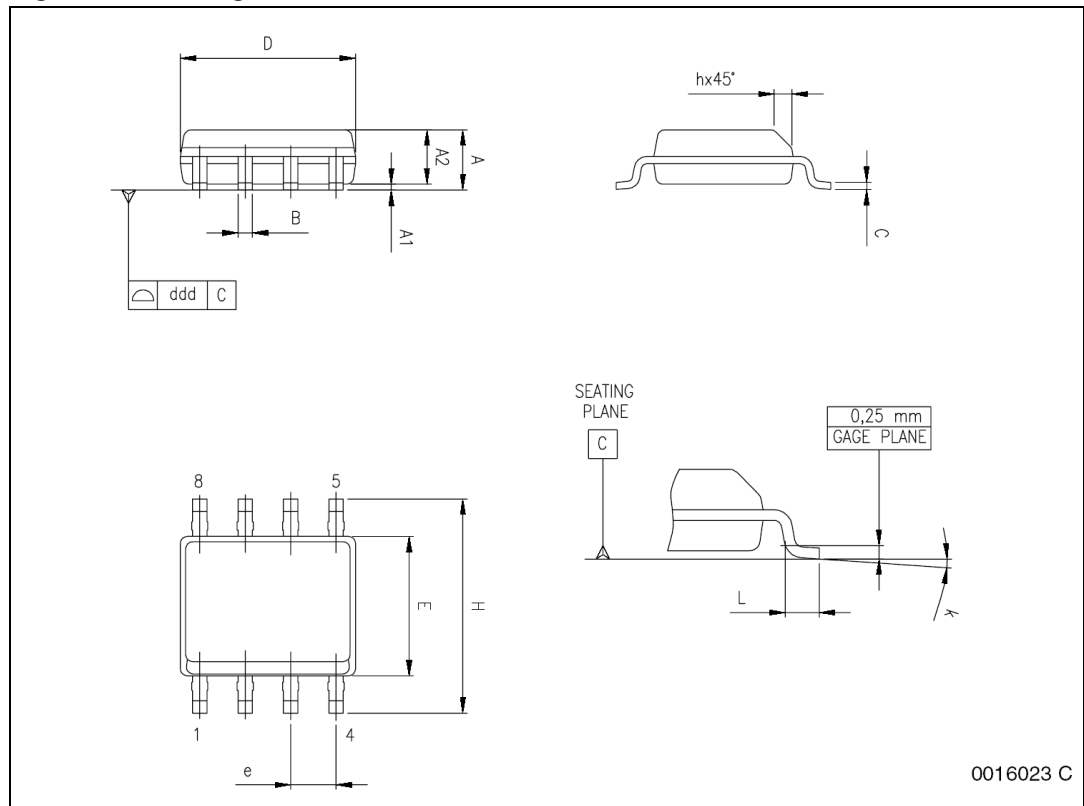


Table 1. SO-8 mechanical data

Dim.	mm.			inch		
	Min	Typ	Max	Min	Typ	Max
A	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.004		0.010
A2	1.10		1.65	0.043		0.065
B	0.33		0.51	0.013		0.020
C	0.19		0.25	0.007		0.010
D (1)	4.80		5.00	0.189		0.197
E	3.80		4.00	0.15		0.157
e		1.27			0.050	
H	5.80		6.20	0.228		0.244
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
k	0° (min.), 8° (max.)					
ddd			0.10			0.004

1. Dimensions D does not include mold flash, protrusions or gate burrs. Mold flash, protrusions or gate burrs shall not exceed 0.15mm (.006inch) in total (both side).

Figure 11. Package dimensions



0016023 C

6 Order information

Table 6. Ordering information

Order codes	Package	Packaging
L6571A	DIP-8	Tube
L6571AD	SO8	
L6571AD013TR		Tape and reel
L6571B	DIP-8	Tube
L6571BD	SO8	
L6571BD013TR		Tape and reel

7 Revision history

Table 7. Document revision history

Date	Revision	Changes
14-Jan-2004	5	No history because migration
15-Jan-2010	6	Updated Table 6 on page 10

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